

DIODE (THREE PHASES BRIDGE TYPE)

DF50AA120/160

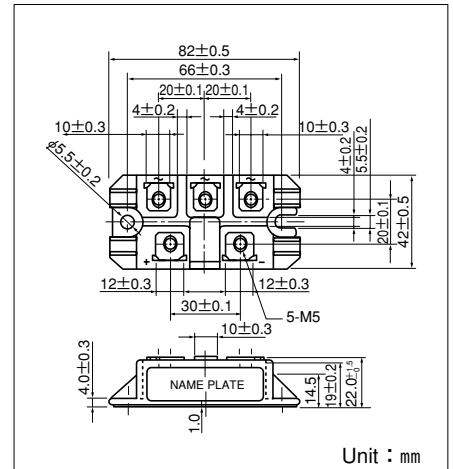
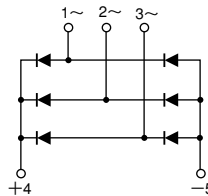
UL;E76102(M)

Power Diode Module DF50AA is designed for three phase full wave rectification, which has six diodes connected in a three phase bridge configuration. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction Output DC current is 50Amp (Tc=114°C) Repetitive peak reverse voltage is up to 1,600V.

- TjMax=150°C
- Isolated mounting base
- High reliability by unique glass passivation

(Applications)

AC, DC Motor Drive/AVR/Switching
-for three phase rectification



Maximum Ratings

(Tj=25°C unless otherwise specified)

Symbol	Item	Ratings		Unit
		DF50AA120	DF50AA160	
V _{RRM}	Repetitive Peak Reverse Voltage	1200	1600	V
V _{RSM}	Non-Repetitive Peak Reverse Voltage	1300	1700	V

Symbol	Item	Conditions	Ratings	Unit	
I _D	Output Current (D.C.)	Three phase full wave. Tc : 114°C	50	A	
I _{FSM}	Surge Forward Current	1cycle, 50/60Hz, peak value, non-repetitive	640/700	A	
I _t	I _t	Value for one cycle of surge current	2000	A ² S	
T _j	Operating Junction Temperature		-40 to +150	°C	
T _{stg}	Storage Temperature		-40 to +125	°C	
V _{iso}	Isolation Breakdown Voltage (R.M.S.)	A.C. 1 minute	2500	V	
	Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	N·m (kgf·cm)
		Terminal (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	
	Mass	Typical Value	160	g	

Electrical Characteristics

Symbol	Item	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
I _{RRM}	Repetitive Peak Reverse Current	Tj=150°C at V _{RRM}			8.0	mA
V _{FM}	Forward Voltage Drop	Tj=25°C, I _{FM} =50A, Inst. measurement			1.2	V
R _{th(j-c)}	Thermal Impedance	Junction to case			0.3	°C/W

